NSN 5961-01-045-3401 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.750 inches and 0.805 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-94
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.045 inches and 1.062 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 nonrepetitive peak reverse voltage
Current Rating Per Characteristic:
70.00 amperes forward current, total rms universal
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 insulated wire lead w/terminal lug
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0